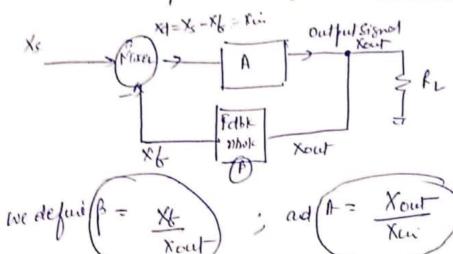


applie cduced eedback

Schematic Representation of feedback aupuffer



$$t_f = \frac{x_{out}}{x_s} = \frac{x_{out}}{x_{ci} + x_b} = \frac{x_{out}}{x_{ui}}$$

$$= \frac{X_{0ut}}{X_{ui}} \times \frac{X_{0ut}}{X_{ui}} = \frac{A}{1 + AB}$$

= # Aj is less than A, In case of negative beedback. Aj > A . - positive feedback - . regenerative.

Advantages of Negative feedback

(1) Gain stability: as Af ~ (A,P), at of Af>>1 tun At depends on B and B depends on praire elements so A in stabilized.

Reduced Non-linear distortion: Df = T+AB.

Reduciol Noise

) Incurred Bondwidth

Increased Input Impedance.

	Coffect of regative feedback on bandwidth
	H
	The effect of regative feedback
	on lower cut off and upper
	The effect of regative feedback on lower cut off ond upper cut of the amplifier is
<u>U</u>	lower cutt off brequercy
	Escontho [f = fc Lt 1+ Amid B]
	LL+ Amid B
	teron the above equation; we
	Can say that lower cut off
300.00	brequercy with feedback is less
	than the lower cutt off frequency
	without beedback by factor (1+ dB)

Scanned by CamScanner

Voltage Burner of the advantages of negative feedback? How do stabilization Q.3. (b) What are the advantages of negative feedback? How do stabilization of negative Feedback? Ans. Negative Feedback (5)

Negative feedback reduces the gain of the amplifier but improves its performance Negative and does not effect the current of the circuit.

Advantages:

1. It improves the gain stability.

2. It reduces non-linear distortion and noise.

3. It increases bandwidth or improved frequency response.

4. It increases input impedance.

5. It reduces output impedance.

Stabilization of gain with negative feedback.

The voltage gain of negative feedback.

$$A_f = \frac{A}{1 + A_{\beta}} \approx \frac{A}{A_{\beta}} = \frac{1}{\beta}$$

The gain A_f is thus independent of internal gain of the amplifier and depends on passive components such as resistors that remain fairly constant. Thus the gain is tabilized. user oircuit and explain its working value of S.

Thermal Runaway: The maximum power that a transistor can dissipate without getting damaged depends largely on the maximum temperature that a collector-base junction can withstand. The rise in the collector-base junction takes place due to two reasons:

- · Due to increase in the ambient temperature and
- Due to the internal heating.

Out of them the internal heating process is cumulative as explained below:

- (i) An increase in collector current $I_{\mathbb{C}}$ increases the power dissipated in the collector-base junction of the transistor.
 - (ii) This will increase the temperature of C-B junction.